

CMOS Pixel Developments in AIDAInnova

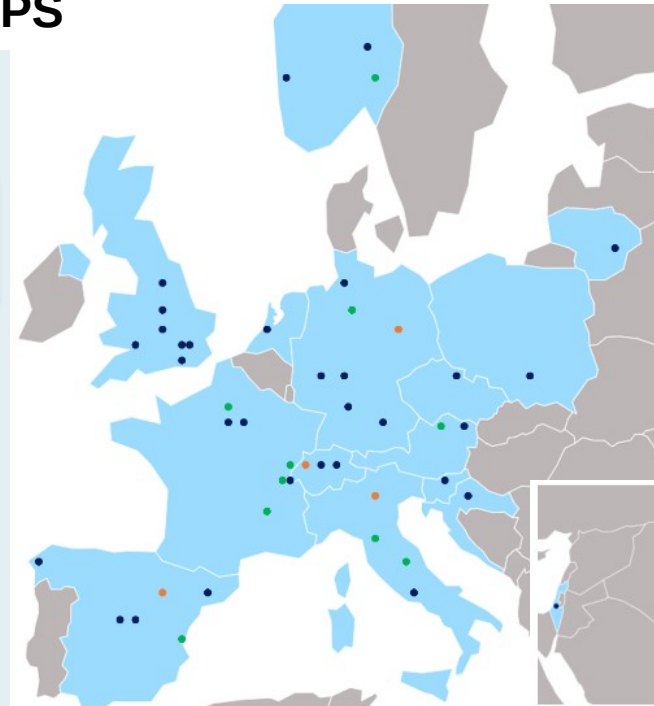
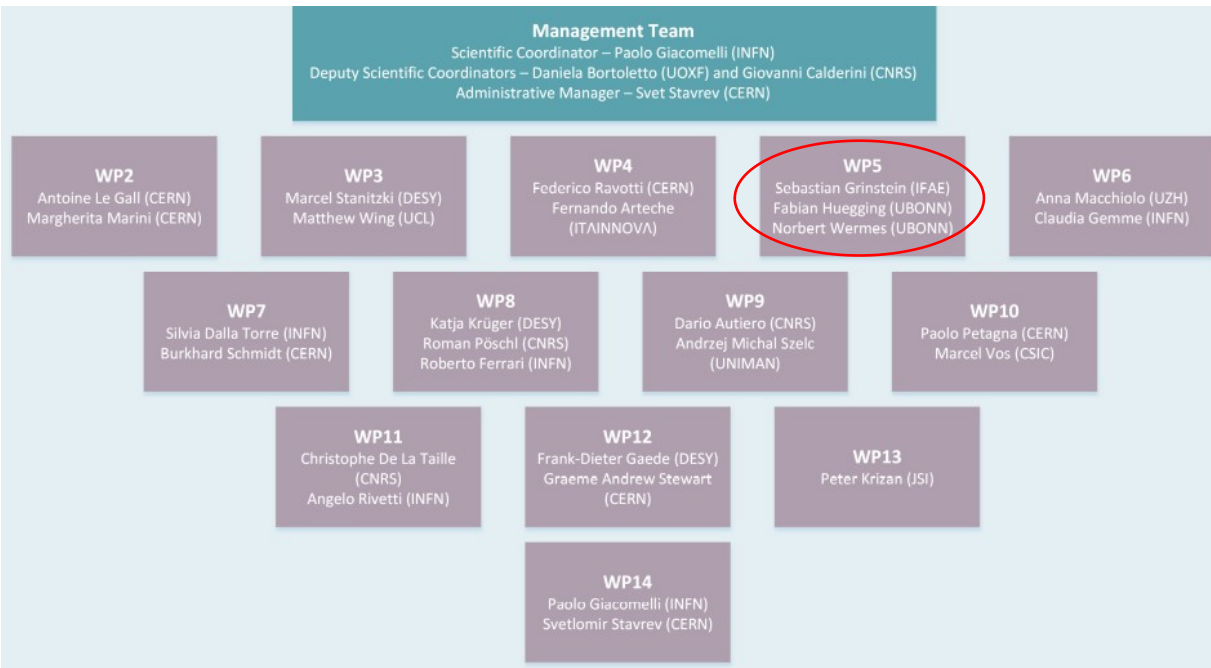
3 July 2023

F. Hügging, N. Wermes (U. Bonn) and S. Grinstein (IFAE-Barcelona)
for the **AIDAInnova WP5 team**

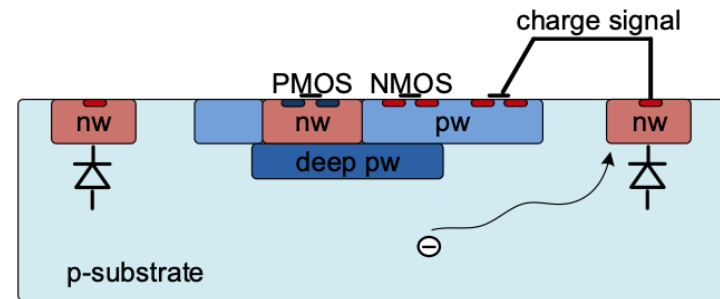
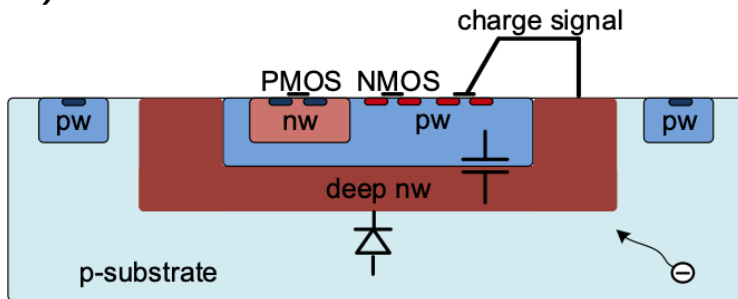


This project has received funding from the European Union's Horizon 2020 research and innovation programme under grant agreement No 101004761.

- AIDAInnova’s goal is to enable **technology advances** mainly for particle physics (upgrades of research infrastructures)
- **European Commission** co-founded project through H2020 program (2021-2025)
- Project involves 8 industrial companies, 3 RTOs and 34 academic institutions in 15 countries, with main target of **common detector projects**
 - Several Work Packages... one dedicated to **DMAPS**



- Two basic approaches to Depleted Monolithic Active Pixel Sensors (DMAPS)
 - a) Large charge collecting electrode, with electronics inside n-well
 - b) Small electrode with the electronics separated



- Within the structure of the AIDAInnova effort (WP5)
 - a) Large electrode mostly targets *radiation hardness*
 - b) Small electrode primarily aims to *high granularity* lower noise and power
- *Categories are only an approximation*: large electrode efforts try to reduce pixel sizes while small electrode approach also targets large depletion regions
- The objective of the WP5 is to design, fabricate and test (before and after irradiation) DMAPS on both these lines

Past and future submissions that will be, or have been, *partially* supported by AIDAInnova (several activities are mostly supported by **other** funds). These are core of WP5 activities.

| Submission | Process | Time-scale | Target | Main Institute | Comment |
|--------------|-----------|------------------------------|-----------------------------|----------------|-------------------------------|
| LF-Monopix 2 | LF 150 nm | v2 produced | rad. hard | Bonn/CPPM | Follow from ATLAS R&D |
| RD50-MPW 3/4 | LF 150 nm | v4 in 0.5-1.0 yr | rad. hard, high granularity | Liverpool | R&D |
| CACTUS | LF 150 nm | mini-CACTUS v2 submitted | timing | CEA | LHC upgrade & beyond |
| TJ-Monopix 2 | TJ 180 nm | v2 produced | high granularity | Bonn | Belle II, follow up by Obelix |
| MALTA 2/3 | TJ 180 nm | v3 in ~0.5 yr | high granularity | CERN | LHC upgrade & beyond |
| ARCADIA | LF 110 nm | next version ~0.5 yr | high granularity | INFN | Demonstrator |
| TJ 65 nm | TJ 65 nm | 2nd iteration just submitted | high granularity | IPHC | R&D, ALICE |

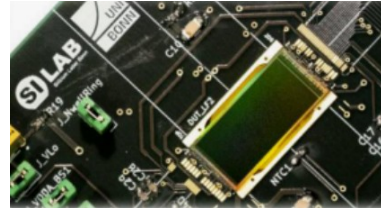
Note:

TJ: Tower

LF: LFoundry

- All activities produced device/prototype during the first phase of the project
- Some lines/sub-projects more advanced than others

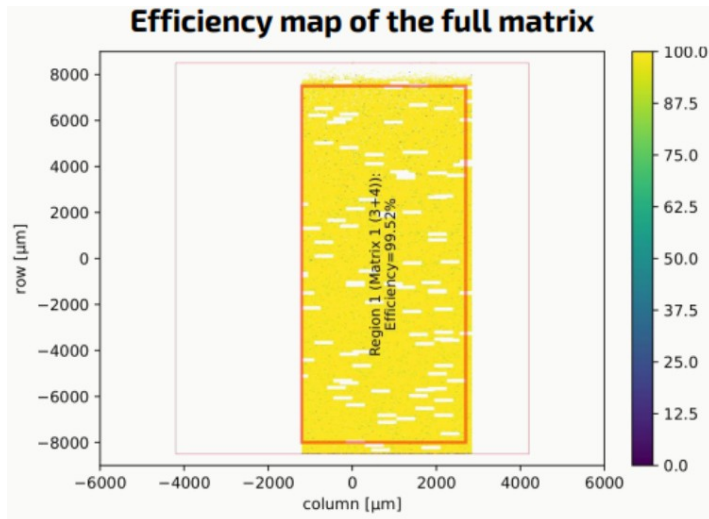
- Successor of LF-Monopix-1
- **LFoundry 150 nm**
- Column drain RO architecture
- 2 kOhm.cm, thinning & back-side processing
- Explored in-pixel circuit flavors
- Beam tests confirmed excellent efficiency before irradiation



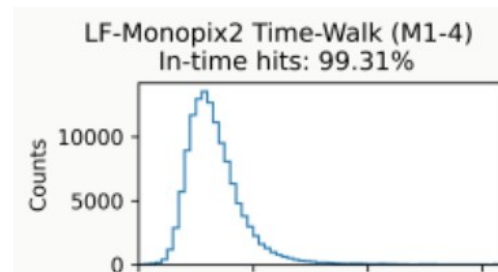
Pixel size: 50x150 μm^2



A cross section of the pixel layout. Deep n-implant forms the charge collection electrode.

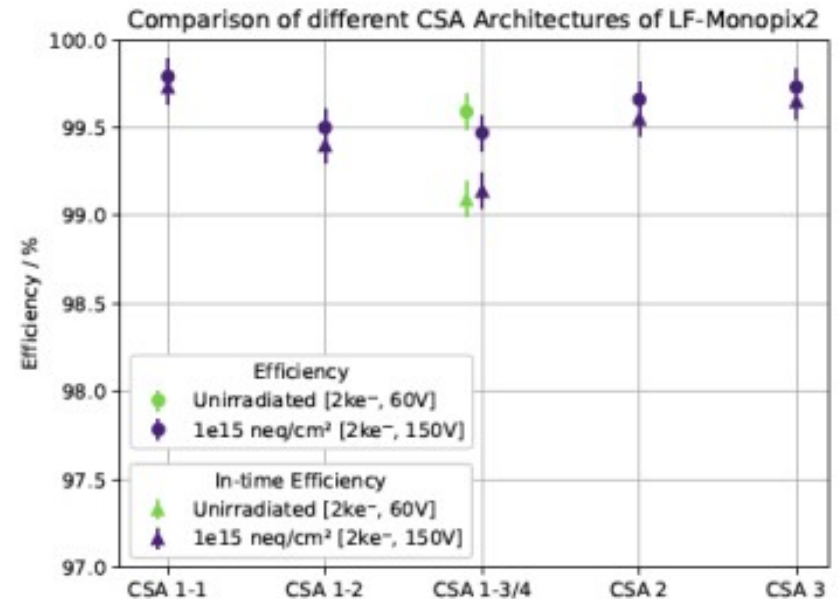


Dingfelder J., et al., NIMA 1034 (2022) 166747

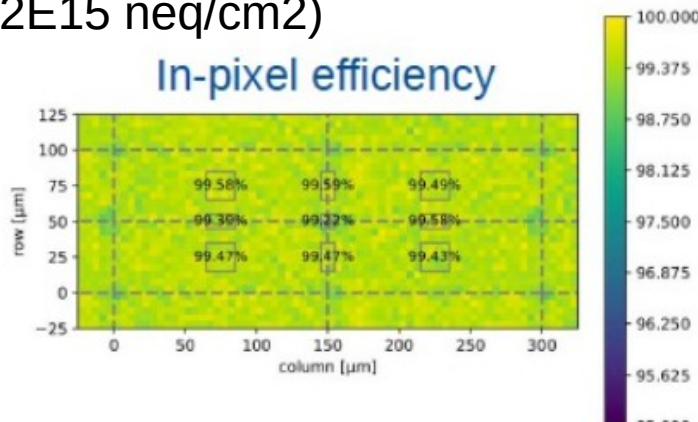


- Devices irradiated and tested with beam

- Irradiated to $1E15$ neq/cm² @ Bonn Cyclotron
- Test-beam characterization followed
 - Very high eff in-time (>99%)
 - no efficiency degradation with respect to non-irradiated
 - Operation threshold ~ 2000 e⁻
 - Plan to study higher fluencies ($2E15$ neq/cm²)



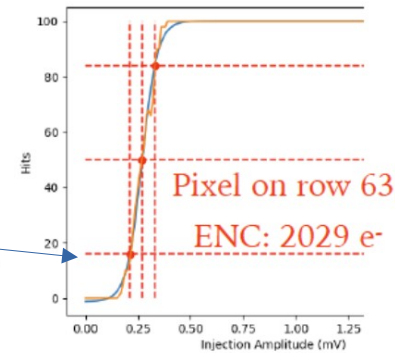
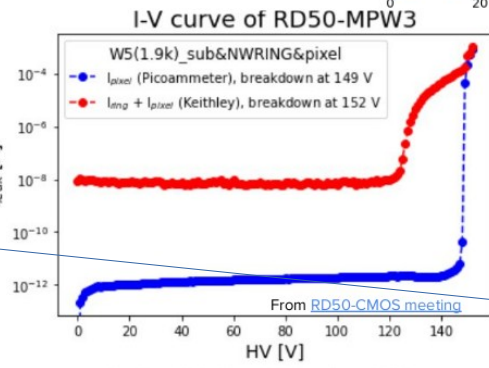
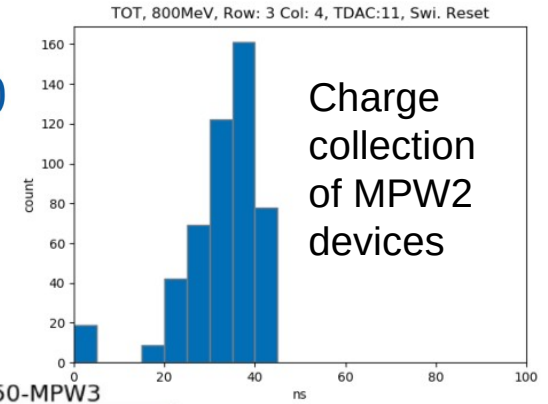
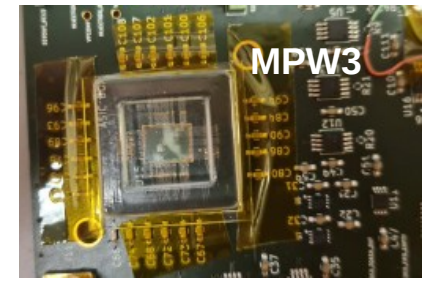
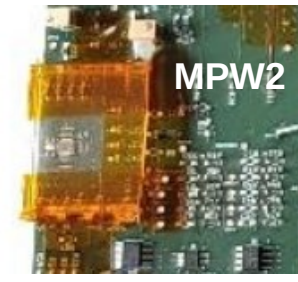
I. Caicedo-Sierra, L. Schall et al. See also Dingfelder J., et al., NIMA 1034 (2022) 166747



Compatible with outer layers of the HL-LHC pixel trackers

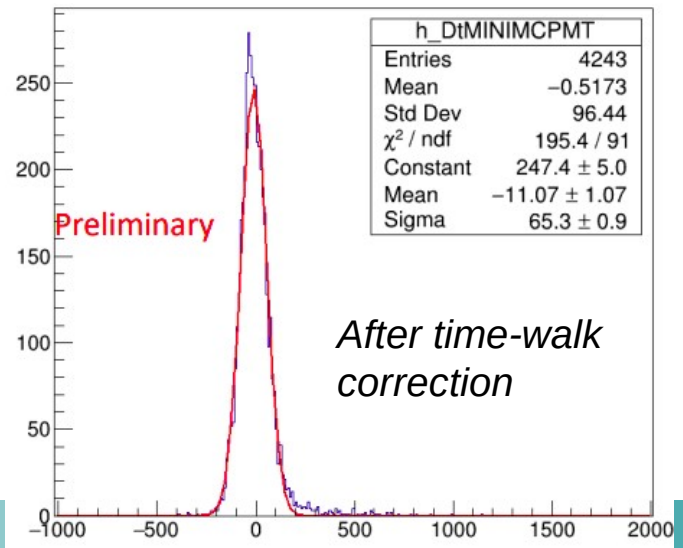
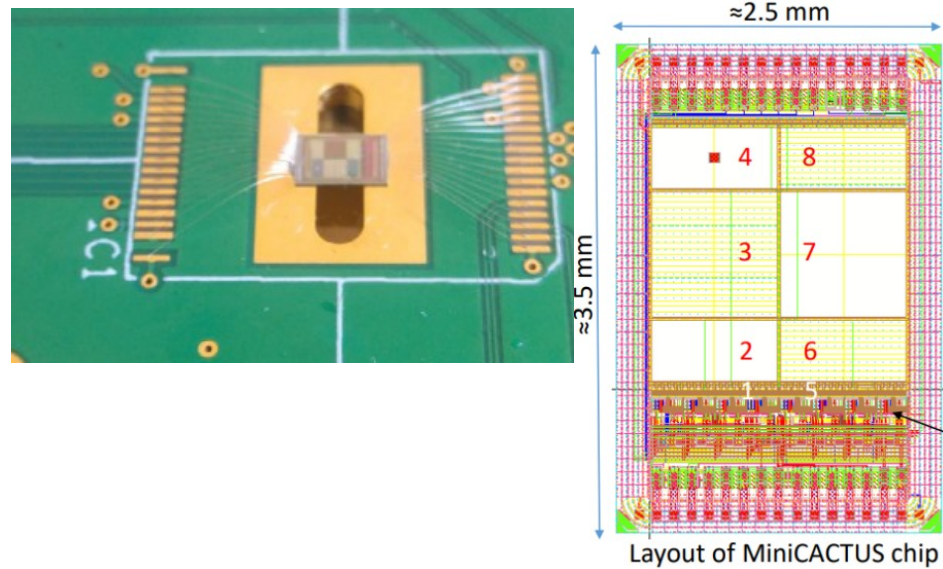
| | ITk Outer Layer |
|------------------|---|
| Occupancy | 1 MHz/mm² |
| Time Res. | 25 ns |
| NIEL | 10^{15} n_{eq}/cm² |
| TID | 80 Mrad |
| Area | 0(10m²) |

- **RD50-MPW2:** small prototype with several test structures
- On LF 150nm, 10-3k Ohm.cm
- Main matrix pixels: $60 \times 60 \mu\text{m}^2$
- In pixel CSA + discriminator, analog readout
- Initial beam tests (UK & Austria)
 - Results indicated expected results in terms of charge collection
- **RD50-MPW3:** fabricated
 - add digital readout (column drain)
 - IV shows $V_{bd} \sim 150\text{V}$
 - High noise, studies on-going



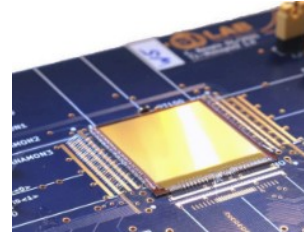
Next RD50-MPW4: with backside processing to improve radiation hardness

- Target is monolithic device that can provide ~ 50 ps **timing resolution**
- LFoundry 150 nm, thinned to 100-200 μm
- Large ($\sim 1 \times 1 \text{ mm}^2$) passive pixels with FE at column level
- **Mini-CACTUS**
 - Small prototype to address limitations of CACTUS (low S/N)
 - Implements different pixel flavors
 - Tested with beam (before irradiation)
 - Achieved ~ 65 ps resolution
- **Second iteration** of mini-cactus
 - Implement different amplifiers types
 - Improved front-end: better discriminator, etc



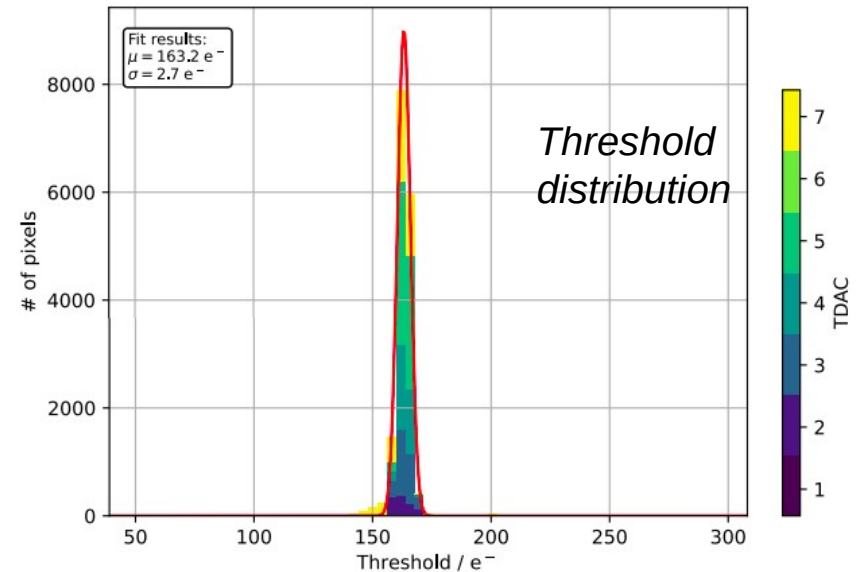
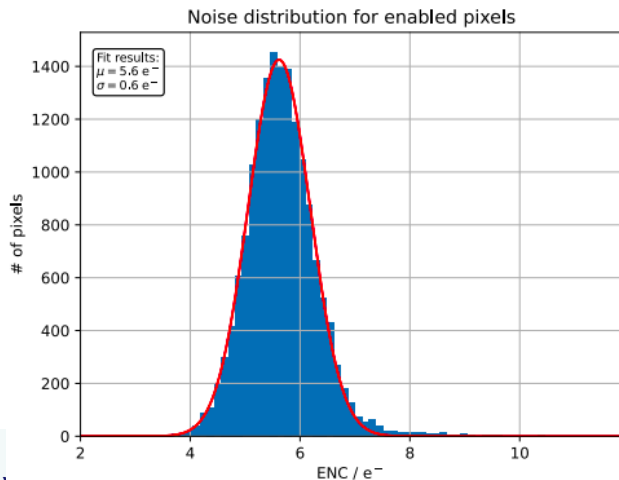
Y. Dangleri et al., <https://doi.org/10.1016/j.nima.2022.167022>

- Successor of TJ-Monopix-1, based on ALPIDE (ALICE ITS upgrade)
- **Tower 180 nm**, various sensing thicknesses (Cz-bulk, epi)
- Column drain RO architecture
- Implements four FE types
 - Cascode transistor to reduce threshold dispersion
 - Improved achievable threshold wrt previous iteration



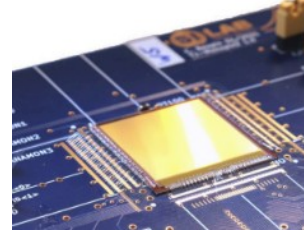
Pixel size: $33 \times 33 \mu\text{m}^2$
 Chip size: $2 \times 2 \text{ cm}^2$

C. Bepin et al., NIMA 040 (2022) 167189



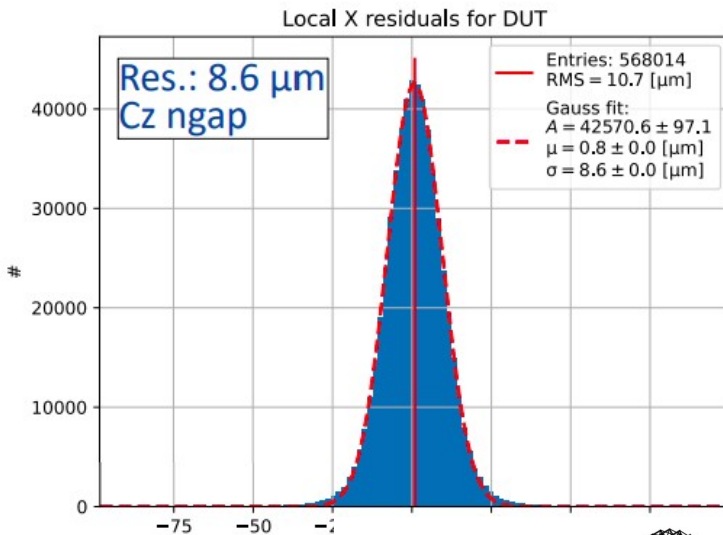
Clear noise reduction with respect to TJ-M1, which had $\sim 30 \text{ e}^-$ noise level.

- About 9 μm position resolution ($\langle \text{cluster size} \rangle \sim 2, \text{Cz}$)
- Excellent efficiency before irradiation
 - Testing of irradiated sensors on-going

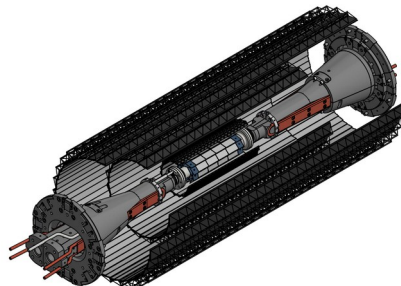
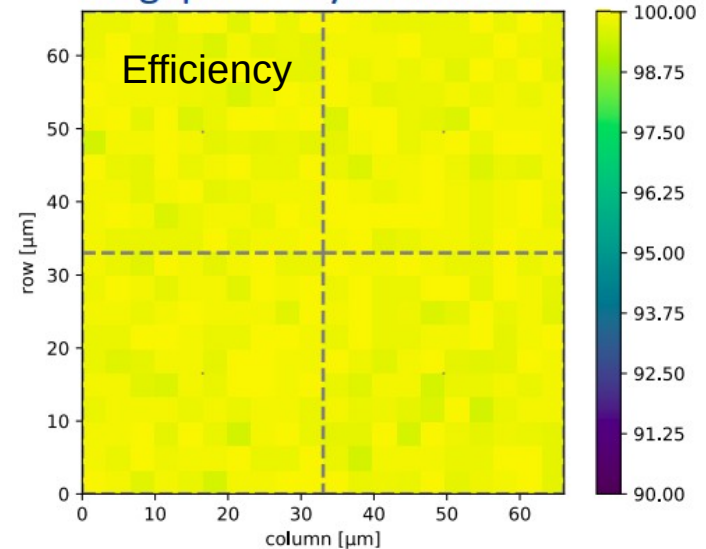


Pixel size: $33 \times 33 \mu\text{m}^2$
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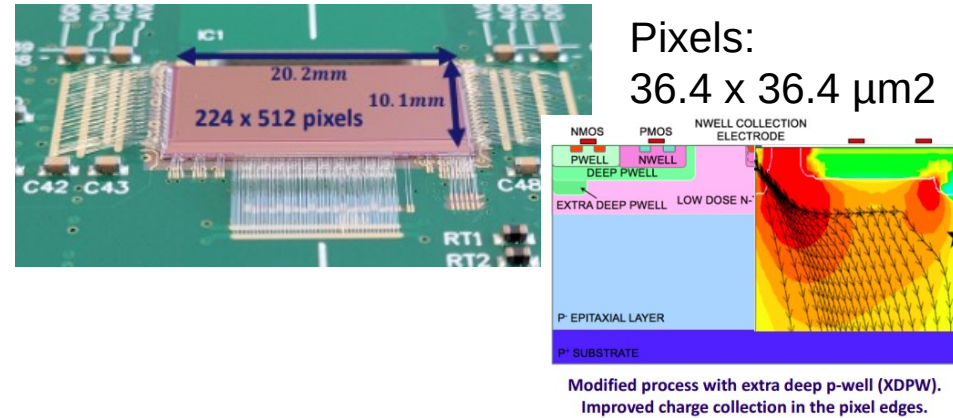


Cz gap in n-layer: 99.79 %

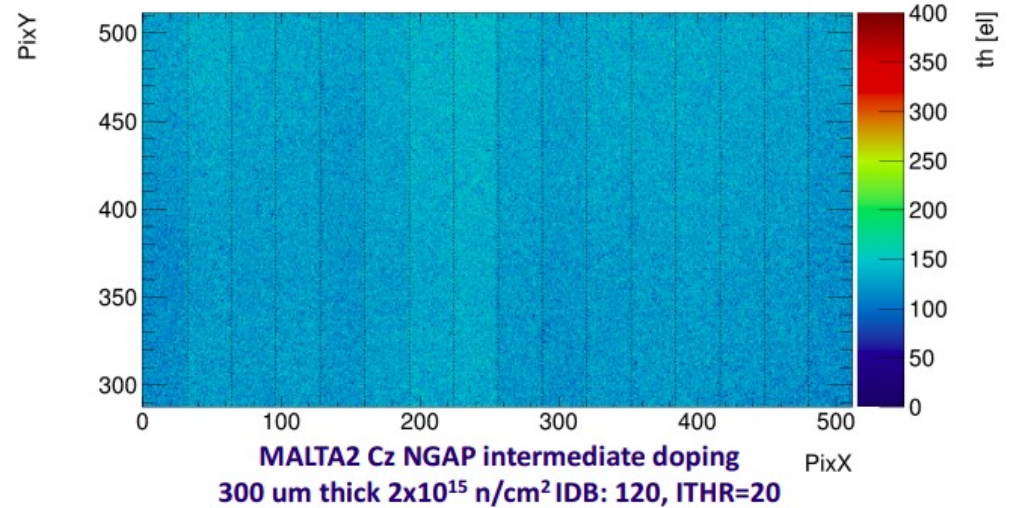
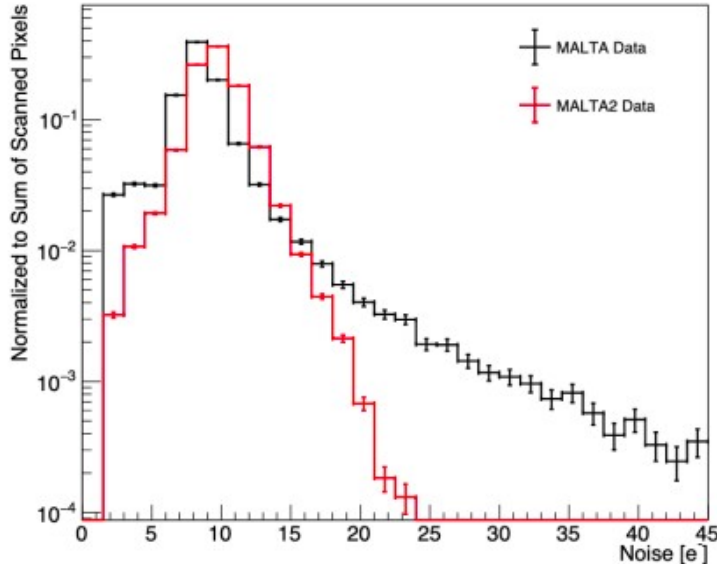


Basis of OBELIX, prototype for Belle-II VXD upgrade

- Follows previous MALTA prototypes
 - Original target ATLAS ITk outer layer
- **Tower 180 nm with process modification** to improve E field
- Fast asynchronous readout (low power)
- Different flavors in 2 substrates (epi, CZ)
- Irradiated up to **3E15 neq/cm²**

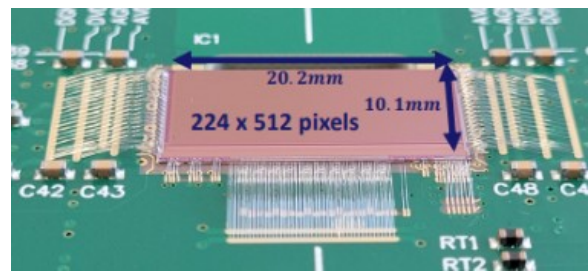


LeBlanc M., et al., NIMA 1041 (2022) 167390



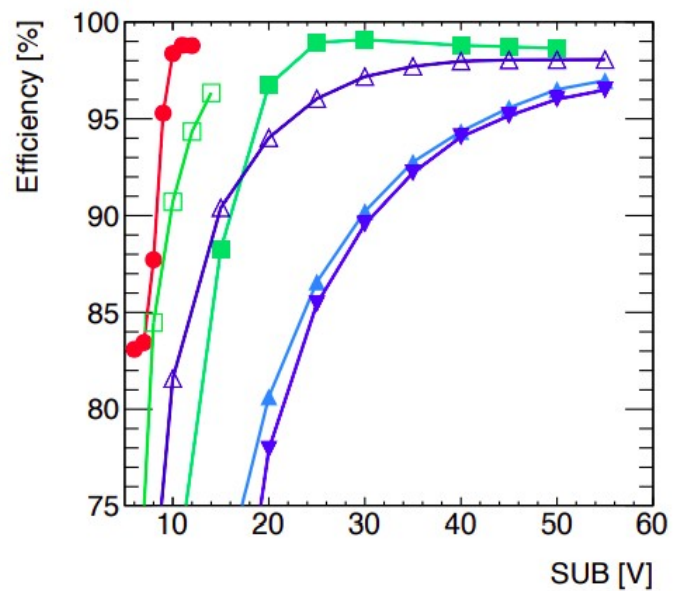
Improved noise wrt previous version and excellent threshold uniformity achieved

- Excellent results from beam tests after $3E15$ neq/cm²
 - Efficiency (>95%)
 - In-time (>95% in 25ns)
- Dual and quad modules fabricated (with MALTA1)

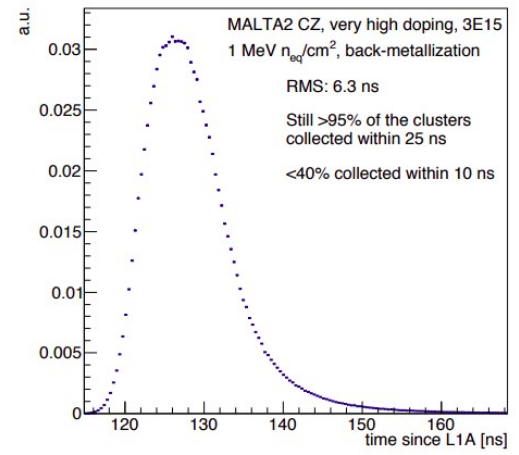


Pixels:
36.4 x 36.4 μ m²

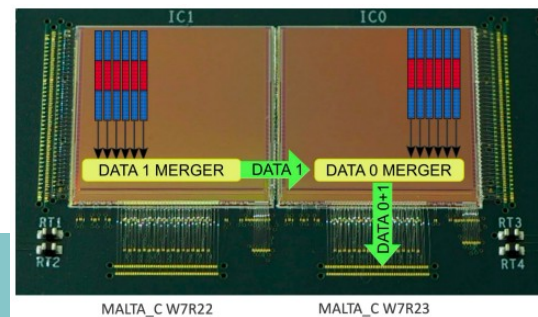
LeBlanc M., et al., NIMA 1041 (2022) 167390



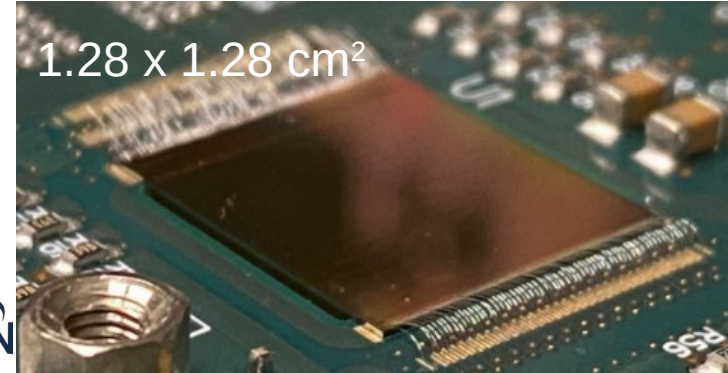
- MALTA2**
CZ Irradiated Samples [$1 \text{ MeV } n_{\text{eq}}/\text{cm}^2$]
- 1E15, Fiducial Area, Conductive Glue
 - 2E15, Fiducial Area, Conductive Glue
 - 2E15, Full Chip, Backside Metallization
 - △ 3E15, Full Chip, Backside Metallization
 - ▲ 3E15, Fiducial Area, Regular Backside
 - ▼ 3E15, Fiducial Area, Regular Backside



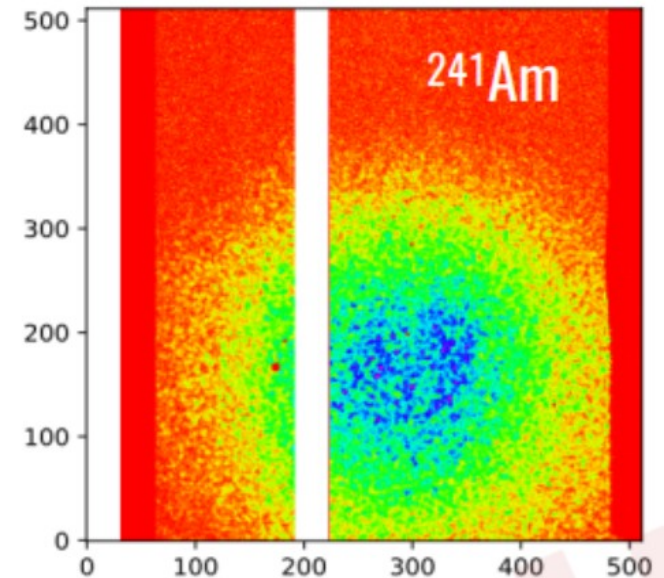
Full reticle MALTA3 design advanced, submission targeted for 2023



- Targets **very low power, small pixel**
- LFoundry 110 nm, largely founded by INFN
- Backside process, 50-500 μm thick
- Triggerless binary readout
- **First demonstrator fabricated**
 - 100 and 200 μm thick
 - Chip communication, injection, etc
 - Initial tests w/ radiation sources and cosmic rays
 - Higher power due to bug
- **MD2 already submitted** and being characterized
- Plan for next submission
 - System-grade main demonstrator chip
 - Gain layer being added for improved timing



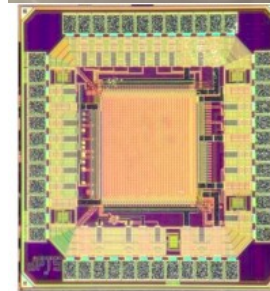
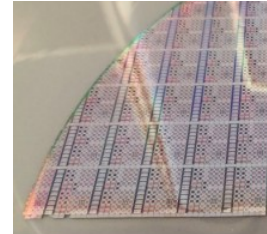
MD1 pixels: 25 x 25 μm^2



M. Rolo (INFN) VCI2022

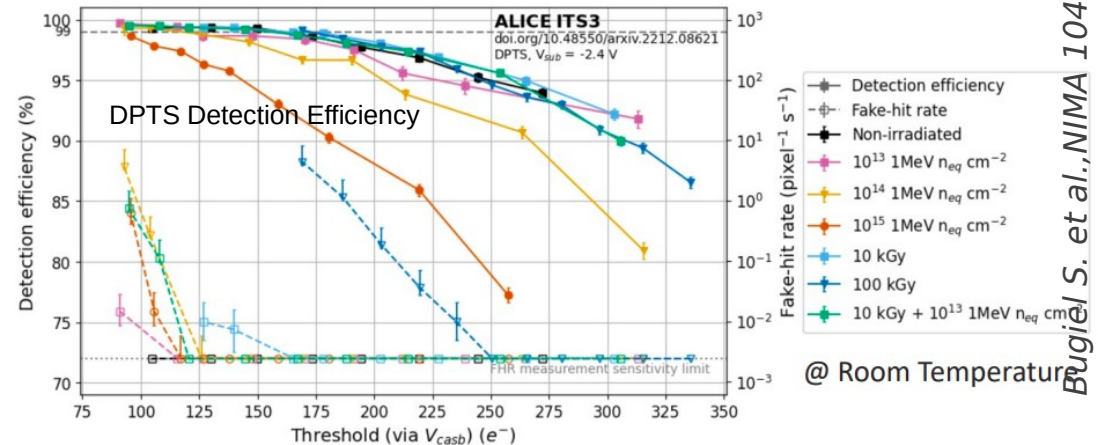
- Explore smaller size tech: **Tower 65 nm**
- Targets excellent position resolution, low mass, high rate, $>1E15$ neq/cm²
- 1st submission in July 2021 (MLR1)
 - Several test blocks included
 - Digital pixel test structure
 - Lab and beam tested
 - Excellent efficiency
- **Second submission**
 - Small prototypes (evolution of versions on MLR1)
 - Two large stitched sensors
 - 25 cm long, stitching
 - Submitted Dec 2022

65 nm test structures and simple chips



DPTS

32 × 32 pixels
15 μm pitch
Asynchronous digital readout
ToT information



Very encouraging results on 65 nm

- In the context of AIDAInnova, many institutions are collaborating in common DMAPS projects, mostly R&D, but some focused on applications
 - See <https://aidainnova.web.cern.ch/wp5>
- Effort focused on two main lines and two foundries (*LF and TJ*)
- Intense effort, not detailed here, DAQ development, irradiation and test-beam efforts, etc
- All research lines with devices to characterize
 - *High granularity, radiation hardness and timing*
 - *Overlap with TaichuPix effort (also in TJ)*
- Specially interesting for CEPC could be activities towards **65 nm** and **timing** with DMAPS

Back Up Slides

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Thanks to all for providing
input for this talk.

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